TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC5093

VHF~UHF Band Low Noise Amplifier Applications

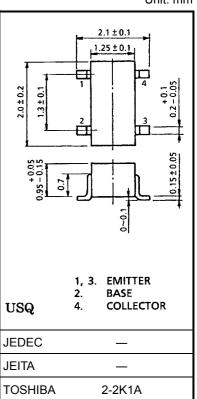
• Low noise figure, high gain.

TOSHIBA

• NF = 1.8dB, $|S_{21e}|^2 = 9.5dB$ (f = 2 GHz)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	20	V	
Collector-emitter voltage	V _{CEO}	10	V	
Emitter-base voltage	V _{EBO}	1.5	V	
Base current	Ι _Β	20	mA	
Collector current	۱ _C	40	mA	
Collector power dissipation	PC	100	mW	
Junction temperature	Тј	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	



Weight: 0.006 g (typ.)

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Transition frequency	f _T	$V_{CE} = 8 \text{ V}, \text{ I}_{C} = 20 \text{ mA}$	7	10	_	GHz	
Incortion agin	S _{21e} ² (1)	$V_{CE} = 8 \text{ V}, \text{ I}_{C} = 20 \text{ mA}, \text{ f} = 1 \text{ GHz}$	12	15	_	dB	
Insertion gain	S _{21e} ² (2)	$V_{CE} = 8 \text{ V}, \text{ I}_{C} = 20 \text{ mA}, \text{ f} = 2 \text{ GHz}$	6.5	9.5	_		
Noise figure	NF (1)	$V_{CE} = 8 V, I_C = 5 mA, f = 1 GHz$ — 1.4		1.4	2.5	dB	
	NF (2)	$V_{CE} = 8 \text{ V}, \text{ I}_{C} = 5 \text{ mA}, \text{ f} = 2 \text{ GHz}$	_	1.8	3	uD	

Electrical Characteristics (Ta = 25°C)

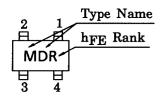
Characteristics Symbol		Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0$	_	_	1	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = 1 V, I_C = 0$		_	1	μA
DC current gain	h _{FE} (Note 1)	$V_{CE} = 8 \text{ V}, \text{ I}_{C} = 20 \text{ mA}$	50	_	160	
Output capacitance	C _{ob}	V _{CB} = 15 V, I _E = 0, f = 1 MHz (Note 2)	_	0.65	1.05	pF
Reverse transfer capacitance	C _{re}	$v_{CB} = 10 v, i_E = 0, i = 1 \text{ MHZ} (NOLE 2)$		0.45	0.95	pF

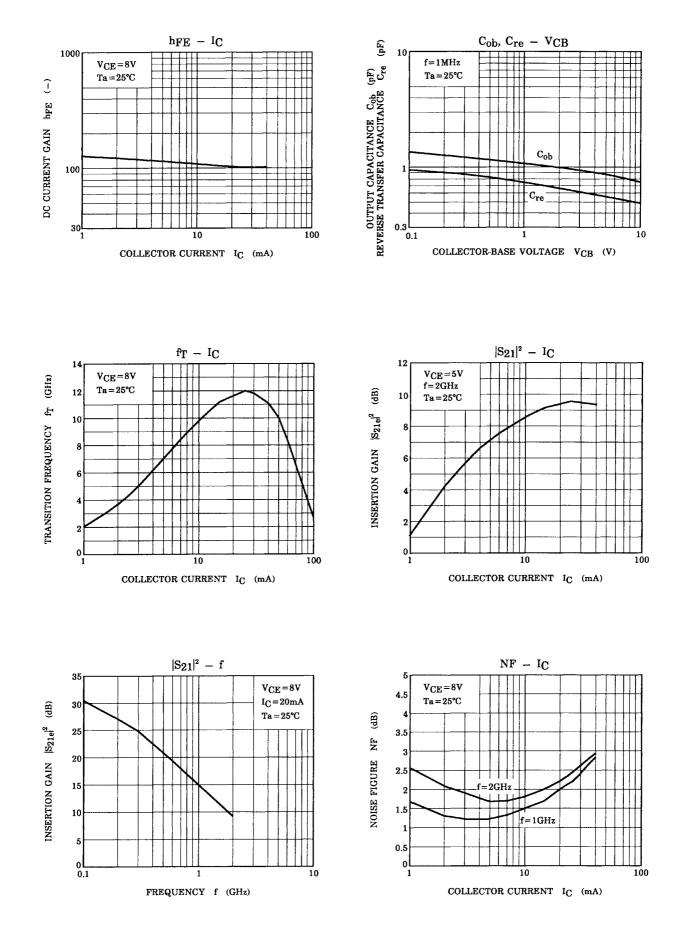
Note 1: h_{FE} classification R: 50~100, O: 80~160

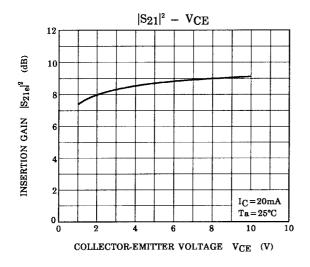
Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

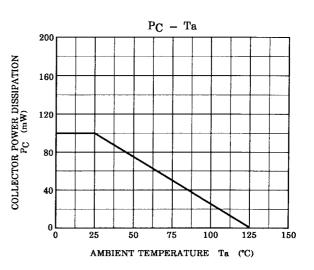
Unit: mm

Marking









S-Parameter $Z_O = 50 \Omega$, Ta = 25°C

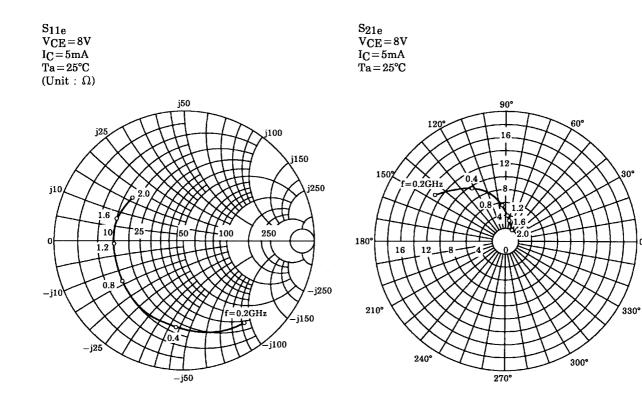
$V_{CE}=8 \ V, \ I_C=5 \ mA$

Frequency	S11		S21		S12		S22	
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.801	-54.4	12.628	145.4	0.047	63.2	0.864	-32.2
400	0.696	-95.6	9.664	121.9	0.072	48.8	0.675	-54.2
600	0.617	-124.7	7.307	106.2	0.083	42.3	0.543	-68.4
800	0.585	-146.3	5.779	95.1	0.090	39.3	0.456	-79.6
1000	0.554	-163.0	4.674	86.8	0.095	39.5	0.400	-88.6
1200	0.545	-176.5	3.902	80.0	0.099	40.4	0.357	-96.8
1400	0.529	171.3	3.350	75.0	0.103	42.5	0.323	-104.5
1600	0.529	161.1	2.929	70.0	0.108	44.8	0.299	-111.0
1800	0.527	150.4	2.612	66.1	0.116	47.1	0.277	-116.5
2000	0.513	141.0	2.366	62.1	0.122	49.6	0.258	-120.3

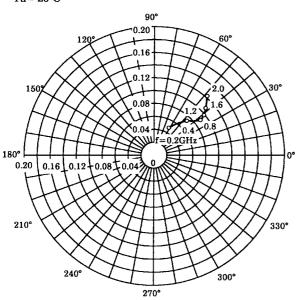
$V_{CE} = 8 V$, $I_C = 20 mA$

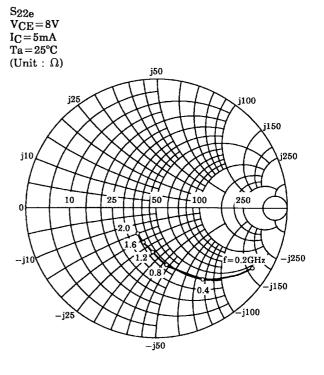
Frequency	S11		S21		S12		S22	
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.556	-95.4	23.034	126.0	0.032	55.7	0.629	-53.5
400	0.521	-137.0	13.888	105.1	0.045	52.0	0.407	-75.8
600	0.505	-160.0	9.597	94.2	0.054	54.0	0.311	-89.3
800	0.505	-174.7	7.272	86.8	0.064	56.4	0.263	-101.3
1000	0.508	172.6	5.797	81.0	0.075	59.0	0.233	-112.0
1200	0.519	163.1	4.800	76.5	0.085	60.4	0.208	-122.9
1400	0.518	153.4	4.119	72.8	0.095	62.0	0.189	-132.7
1600	0.525	144.3	3.603	69.1	0.106	63.2	0.172	-141.7
1800	0.532	135.6	3.231	66.4	0.119	63.8	0.153	-149.3
2000	0.523	125.9	2.952	62.8	0.131	64.6	0.131	-153.9

0°





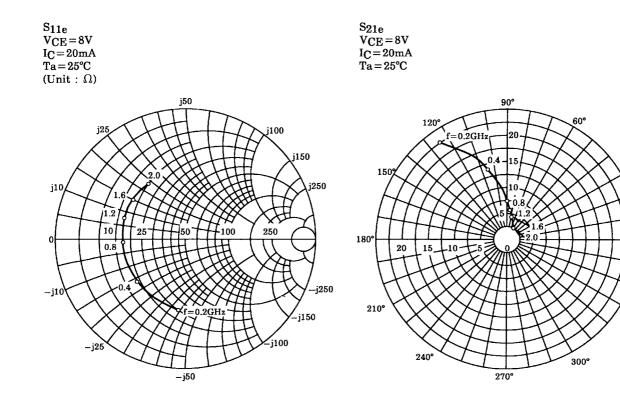




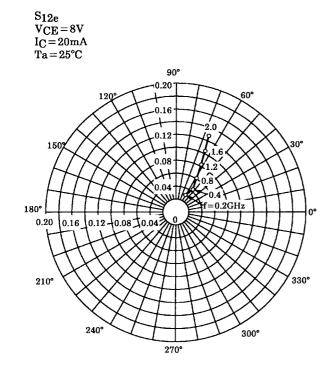
30

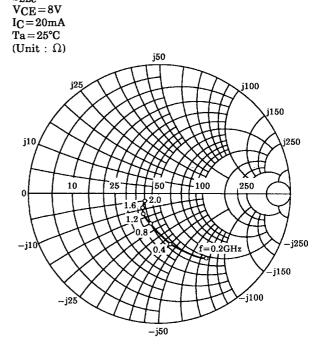
0°

, 330°



S_{22e}





RESTRICTIONS ON PRODUCT USE

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.